54150/DM54150/DM74150, 54151A/DM54151A/DM74151A Data Selectors/Multiplexers

General Description

These data selectors/multiplexers contain full on-chip decoding to select the desired data source. The 150 selects one-of-sixteen data sources; the 151A selects one-of-eight data sources. The 150 and 151A have a strobe input which must be at a low logic level to enable these devices. A high level at the strobe forces the W output high and the Y output (as applicable) low.

The 151A features complementary W and Y outputs, whereas the 150 has an inverted (W) output only.

The 151A incorporates address buffers which have symmetrical propagation delay times through the complementary paths. This reduces the possibility of transients occurring at the output(s) due to changes made at the select inputs, even when the 151A outputs are enabled (i.e., strobe low).

Features

- 150 selects one-of-sixteen data lines
- 151A selects one-of-eight data lines
- Performs parallel-to-serial conversion
- Permits multiplexing from N lines to one line
- Also for use as Boolean function generator
- Typical average propagation delay time, data input to W output

150 11 ns 151A 9 ns

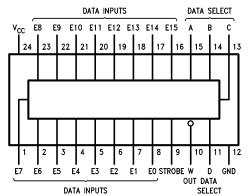
■ Typical power dissipation

150 200 mW 151A 135 mW

 Alternate Military/Aerospace device (54150, 54151A) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

Connection Diagrams

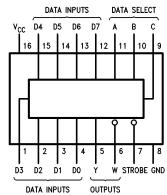
Dual-In-Line Package



TL/F/6546-1 Order Number 54150DQMB, 54150FMQB,

DM54150J or DM74150N See NS Package Number J24A, N24A or W24C

Dual-In-Line Package



TL/F/6546-2

54150/DM54150/DM74150, 54151A/DM54151A/DM74151A Data Selectors/Multiplexers

Order Number 54151ADMQB, 54151AFMQB, DM54151AJ, DM54151AW or DM74151AN See NS Package Number J16A, N16E or W16A

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Input Voltage 5.5V Operating Free Air Temperature Range

DM54 and 54 -55°C to +125°C DM74 0°C to +70°C

-65°C to +150°C Storage Temperature Range

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM54150			DM74150			Units
	Tarameter	Min	Nom	Max	Min	Nom	Max	
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.8			0.8	V
I _{OH}	High Level Output Current			-0.8			-0.8	mA
I _{OL}	Low Level Output Current			16			16	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

'150 Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ (Note 1)	Max	Units	
V_{I}	Input Clamp Voltage	$V_{CC} = Min, I_I =$	-12 mA			-1.5	٧
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max, V_{IH} = Min$		2.4			V
V_{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = V_{IH} = Min, V_{IL} = $			0.4	V	
I _I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA
I _{IH}	High Level Input Current	V _{CC} = Max, V _I =	$V_{CC} = Max, V_I = 2.4V$			40	μΑ
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-1.6	mA
los	Short Circuit	V _{CC} = Max DM54		-20		-55	mA
	Output Current	(Note 2)	DM74	-18		-55	"''
I _{CC}	Supply Current	V _{CC} = Max, (Not	te 3)		40	68	mA

Note 1: All typicals are at $V_{CC}=5V$, $T_A=25^{\circ}C$.

Note 2: Not more than one output should be shorted at a time.

Note 3: I_{CC} is measured with the strobe and data select inputs at 4.5V, all other inputs and outputs open.

'150 Switching Characteristics at $V_{CC}=5V$ and $T_A=25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	From (Input)	$R_L = 400\Omega$	Units	
Symbol	raiametei	To (Output)	Min	Max	Office
t _{PLH}	Propagation Delay Time Low to High Level Output	Select to W		35	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Select to W		33	ns
^t PLH	Propagation Delay Time Low to High Level Output	Strobe to W		24	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Strobe to W		30	ns
^t PLH	Propagation Delay Time Low to High Level Output	E0-E15 to W		20	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	E0-E15 to W		14	ns

Recommended Operating Conditions

Symbol	Parameter	DM54151A			DM74151A			Units
	Farameter	Min	Nom	Max	Min	Nom	Max	Office
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.8			0.8	V
Іон	High Level Output Current			-0.8			-0.8	mA
I _{OL}	Low Level Output Current			16			16	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

'151A Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ (Note 1)	Max	Units	
VI	Input Clamp Voltage	$V_{CC} = Min, I_I =$	-12 mA			-1.5	V
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = V_{IL} = Max, V_{IH} = V_{IL} = $	2.4			V	
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = V_{IH} = Min, V_{IL} = V_{IH} = Min, V_{IL} = V_{IH} = V_{IH} = V_{IL} = V_{IH} = V_{I$			0.4	V	
I _I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA
I _{IH}	High Level Input Current	V _{CC} = Max, V _I =	$V_{CC} = Max, V_I = 2.4V$			40	μΑ
I _{IL}	Low Level Input Current	V _{CC} = Max, V _I =	$V_{CC} = Max, V_I = 0.4V$			-1.6	mA
los	Short Circuit	V _{CC} = Max DM54		-20		-55	mA
	Output Current	(Note 2)	DM74	-18		-55	11171
Icc	Supply Current	V _{CC} = Max, (Note 3)			27	48	mA

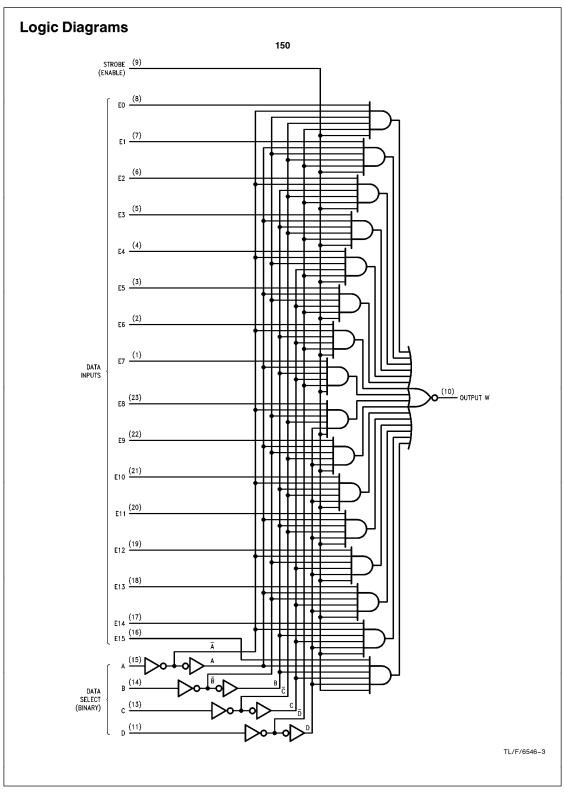
Note 1: All typicals are at $V_{CC}=5V$, $T_A=25^{\circ}C$.

Note 2: Not more than one output should be shorted at a time.

Note 3: I_{CC} is measured with the strobe and data select inputs at 4.5V, all other inputs and outputs open.

'151A Switching Characteristics at $V_{CC}=5V$ and $T_A=25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

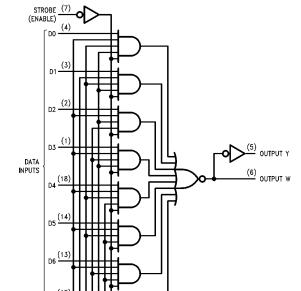
Symbol	Parameter	From (Input)	$R_L = 400\Omega$	Units	
Symbol	raiametei	To (Output)	Min	Max	
t _{PLH}	Propagation Delay Time Low to High Level Output	Select (4 Levels) to Y		38	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Select (4 Levels) to Y		30	ns
t _{PLH}	Propagation Delay Time Low to High Level Output	Select (3 Levels) to W		26	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Select (3 Levels) to W		30	ns
t _{PLH}	Propagation Delay Time Low to High Level Output	Strobe to Y		33	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Strobe to Y		30	ns
t _{PLH}	Propagation Delay Time Low to High Level Output	Strobe to W		21	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Strobe to W		25	ns
t _{PLH}	Propagation Delay Time Low to High Level Output	D0-D7 to Y		24	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	D0-D7 to Y		24	ns
^t PLH	Propagation Delay Time Low to High Level Output	D0-D7 to W		14	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	D0-D7 to W		14	ns

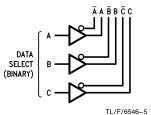


Logic Diagrams



Address Buffers for 54151A/74151A





TL/F/6546-4

See Address Buffers Below

Function Tables

54150/74150

	Inputs						
	Select			Strobe	Outputs W		
D	С	В	Α	S			
Х	Х	Х	Х	Н	Н		
L	L	L	L	L	E0		
L	L	L	Н	L	E1		
L	L	Н	L	L	E2		
L	L	Н	Н	L	E3		
L	Н	L	L	L	E4		
L	Н	L	Н	L	E5		
L	Н	Н	L	L	E6		
L	Н	Н	Н	L	E7		
Н	L	L	L	L	E8		
Н	L	L	Н	L	E9		
Н	L	Н	L	L	E10		
Н	L	Н	Н	L	E11		
Н	Н	L	L	L	E12		
Н	Н	L	Н	L	E13		
Н	Н	Н	L	L	E14		
Н	Н	Н	Н	L	E15		

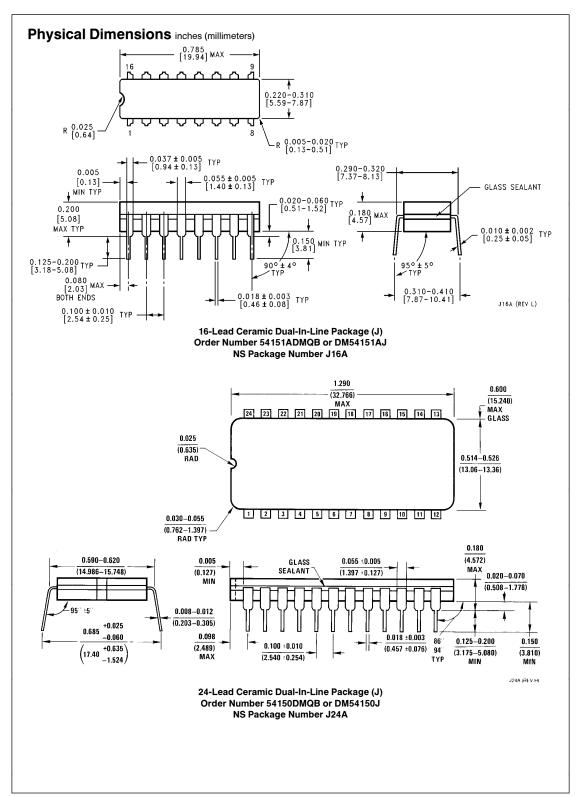
 $H \,=\, \text{High Level, L} \,=\, \text{Low Level, X} \,=\, \text{Don't Care}$

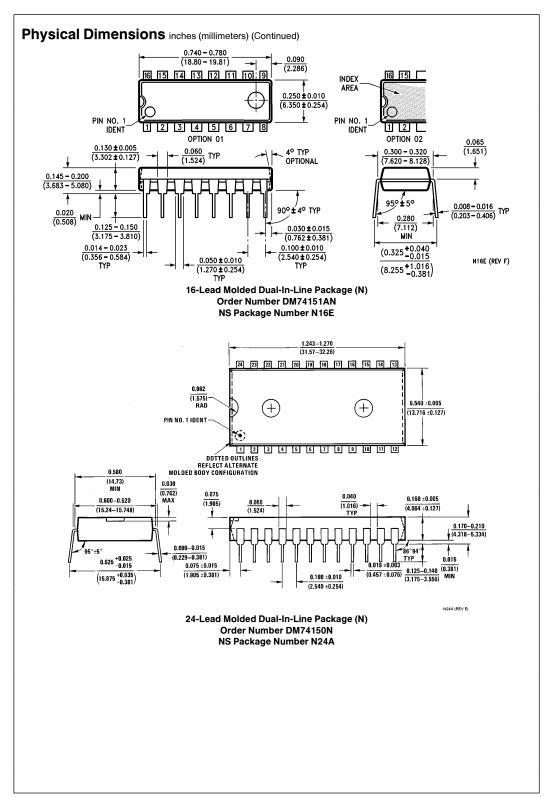
 $\overline{E0},\,\overline{E1}\,\ldots\,\overline{E15}\,=\,$ the complement of the level of the respective E input

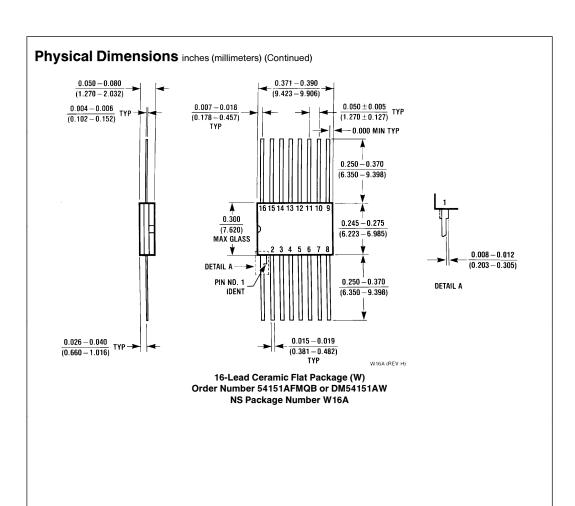
54151A/75151A

	I	Out	puts				
	Select		Select Strobe				w
С	В	Α	S	•			
Х	х	Х	Н	L	Н		
L	L	L	L	D0	D0		
L	L	Н	L	D1	D1		
L	Н	L	L	D2	D2		
L	Н	Н	L	D3	D3		
Н	L	L	L	D4	D4		
Н	L	Н	L	D5	D5		
Н	Н	L	L	D6	D6		
Н	Н	Н	L	D7	D7		

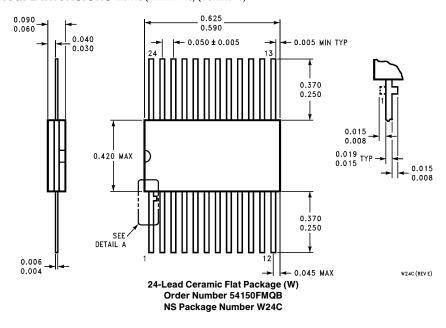
H = High Level, L = Low Level, X = Don't CareD0, D1 \dots D7 = the level of the respective D input







Physical Dimensions inches (millimeters) (Continued)



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National Semiconductor

National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

National Semiconductor Europe

Fax: (+49) 0-180-530 85 86 Fax: (+49) 0-180-530 85 86 Email: cnjwge@tevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tel: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 35 Italiano Tel: (+49) 0-180-534 16 80 National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block, Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408